

N-Channel Enhancement Mode Power MOSFET

Product Summary

- V_{DS}= 20V,I_D= 30A
- $R_{DS(on)}$ < 10m Ω @ V_{GS} = 4.5V
- $R_{DS(on)}$ < 15m Ω @ V_{GS} = 2.5V

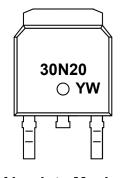
Features

- Advanced Trench Technology
- 100% Avalanche Tested
- RoHS Compliant
- Halogen and Antimony Free
- Moisture Sensitivity Level 3

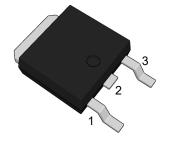
Application

- Load Switch
- PWM Application
- Power Management

Marking Code



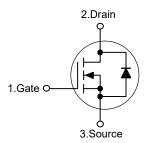
TO-252



(Top View)

Pin	Pin Description	
1	Gate	
2	Drain	
3	Source	

Schematic Diagram



Absolute Maximum Ratings

Ratings at 25°C case temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±12	V
Drain Current-Continuous	I _D	30	А
Drain Current-Pulsed Note1	Ірм	120	А
Maximum Power Dissipation	P _D	25	W
Single Pulse Avalanche Energy Note2	E _{AS}	33	mJ
Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Thermal Characteristics

Thermal Resistance, Junction-to-Case	R _{eJC}	5	°C/W



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Electrical Characteristics

(T_J=25°C unless otherwise specified)

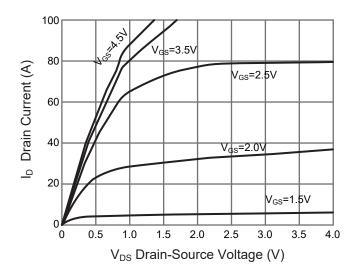
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Static Characteristics				•	ı	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V,I _D =250μA	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V			1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V,V _{DS} =0V			±100	nA
Gate Threshold Voltage Note3	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	0.4	0.7	1.0	V
Duning Courses On Duninters	_	V _{GS} =4.5V,I _D =15A		7	10	mΩ
Drain-Source On-Resistance Note3	R _{DS(on)}	V _{GS} =2.5V,I _D =10A		10	15	mΩ
Forward Transconductance Note3	G FS	V _{DS} =5V,I _D =2A		9		S
Dynamic Characteristics			•		•	
Input Capacitance	C _{iss}			1072		pF
Output Capacitance	Coss	V _{DS} =10V,V _{GS} =0V,f=1MHz		159		pF
Reverse Transfer Capacitance	C _{rss}			141		pF
Gate Resistance	Rg	V _{DS} =0V,V _{GS} =0V,f=1MHz		1.65		Ω
Total Gate Charge	Qg	V _{DS} =10V, I _D =15A, V _{GS} =4.5V		13		nC
Gate-Source Charge	Q _{gs}			2.5		nC
Gate-Drain Charge	Q _{gd}			3.5		nC
Switching Characteristics			•		1	1
Turn-on Delay Time	t _{d(on)}	V_{DD} =10V, I_{D} =15A, V_{GS} =4.5V, R_{GEN} =3 Ω		8		nS
Turn-on Rise Time	t _r			19		nS
Turn-off Delay Time	t _{d(off)}			30		nS
Turn-off Fall Time	t _f			11		nS
Source-Drain Diode Characteristic	es			•		
Diode Forward Voltage Note3	V _{SD}	V _{GS} =0V,I _S =30A			1.2	V
Diode Forward Current	Is				30	Α

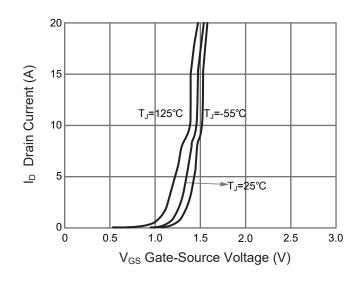
Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

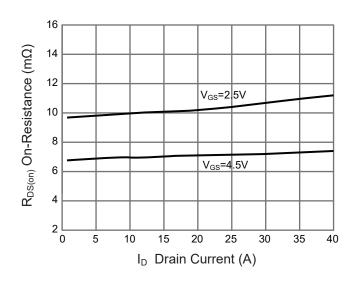
- 2. EAS condition: T_J =25°C, V_{DD} =15V, V_G =10V, R_G =25 Ω , L=0.5mH, I_{AS} =11.5A
- 3. Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%

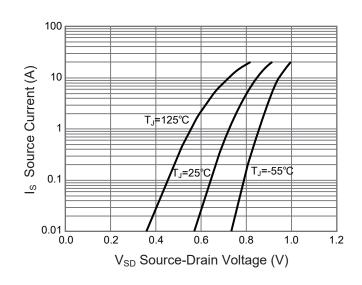


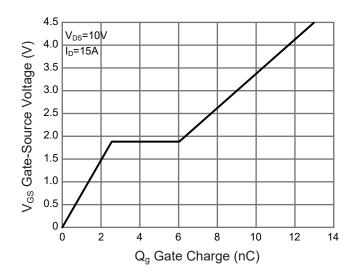
Typical Characteristic Curves

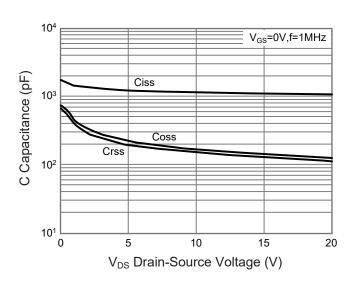










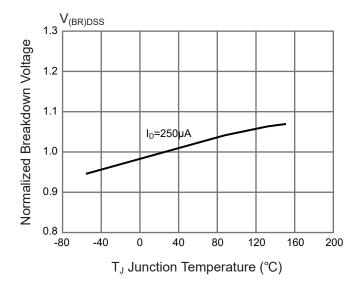


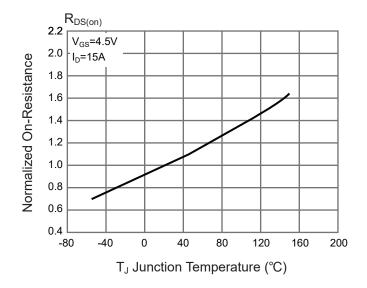


TN30N20TE

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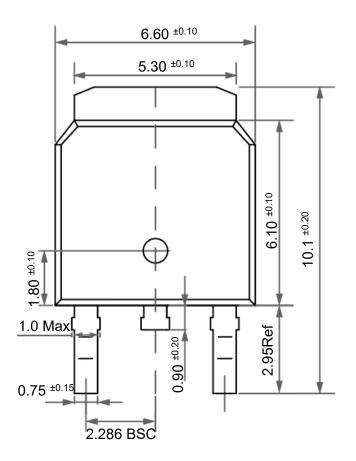


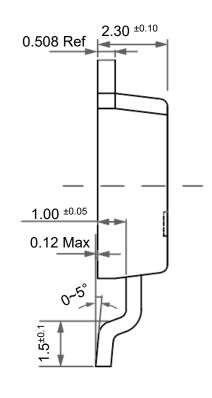




Package Outline

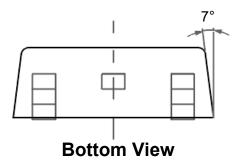
TO-252 Dimensions in mm





Front View

Side View



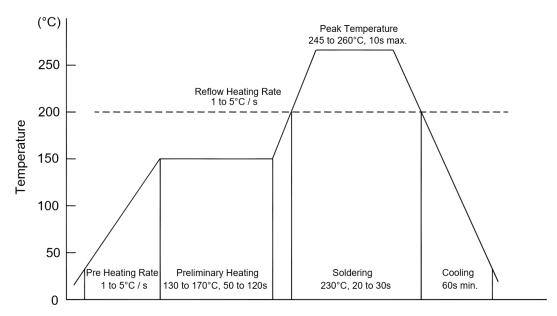
Ordering Information

Device	Package	Shipping
TN30N20TE	TO-252	2,500PCS/Reel&13inches



Conditions of Soldering and Storage

Recommended condition of reflow soldering



Recommended peak temperature is over 245°C. If peak temperature is below 245°C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

Temperature: 300°C

Time: 3s max.Times: one time

♦ Storage conditions

Temperature

5 to 40°C

Humidity

30 to 80% RH

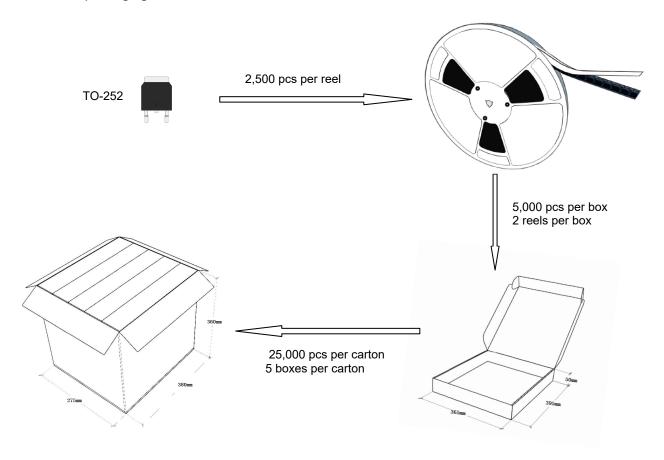
Recommended period

One year after manufacturing

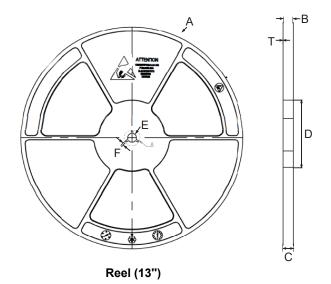


Package Specifications

The method of packaging



♦ reel data

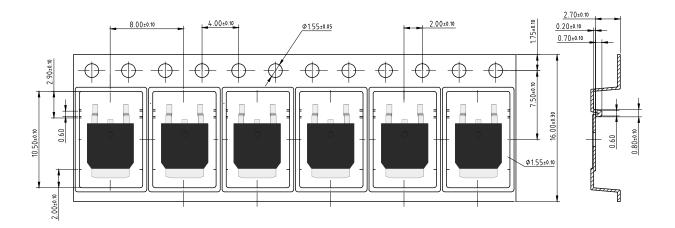


Symbol	Value(unit:mm)	
A	Ф330.2±1	
В	17±0.5	
С	21.2±2	
D	Ф100±0.5	
E	Ф13.4±0.2	
F	2.3±0.2	
Т	2.1±0.2	



N-Channel Enhancement Mode Power MOSFET

♦ Embossed tape data





TN30N20TE

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Contact Information

For additional information, please contact your local Sales Representative.



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Product Specification Statement

The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. TANI shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and TANI assumes no responsibility for the application of the product. TANI strives to provide accurate and up -to- date information the best of our ability. However, due to technical, human, or other reasons, TANI cannot guarantee that the information provided in the product specification is entirely accurate and error-free. TANI shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications.

TANI reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with TANI to ensure that the prod uct specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult TANI in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. TANI shall assume no responsibility for any consequences resulting from such usage.

Users should also comply with relevant laws, regulations, policies, and standards when using the product specification. Users are responsible for the risks and liabilities arising from the use of the product specification and must ensure that it is not used for illegal purposes. Additionally, users should respect the intellectual property rights related to the product specification and refrain from infringing upon any third- party legal rights. TANI shall assume no responsibility for any disputes or controv ersies arising from the above-mentioned issues in any form.